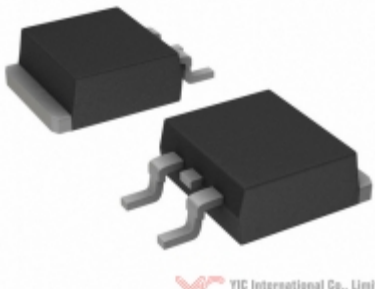










	<h2 style="color: red;">FQB32N12V2TM</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">FQB32N12V2TM</a>
	<b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a>
	<b>Teil der Beschreibung:</b> MOSFET N-CH 120V 32A D2PAK
	<b>Datenblätter:</b>  <a href="#">FQB32N12V2TM.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 33216 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	<a href="#">FQB32N12V2TM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 120V 32A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	33216 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 150W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	120V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	32A (Tc)
Rds On (Max) @ Id, Vgs	50 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	53nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1860pF @ 25V
Verpackung	Tape & Reel (TR)













































FQB32N12V2TM ist neu im Original, Suche FQB32N12V2TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB32N12V2TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB32N12V2TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQB32N20C</b> F FQB32N20C F	 <b>FQB32N12V2TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 120V 32A D2PAK	 <b>FQB30N06TM</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 30A D2PAK	 <b>FQB32N20</b> FSC FQB32N20 FSC
 <b>FQB32N12V2</b> FSC FQB32N12V2 FSC	 <b>FQB30N06TM_NL</b> FAIRCHILD	 <b>FQB30N06TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 30A D2PAK	 <b>FQB32N20CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 28A D2PAK

### heiße Teile

Mehr

 FQB25N33	 FQB25N33TM	 FQB25N33TM	D FQB25N33TM_F085	 FQB27N25TM
 FQB27P06	 FQB27P06TM	D FQB27P06TM	 FQB2N50C	 FQB2N60TM
 FQB2N60TM	 FQB2N80TM	 FQB2N80TM	 FQB2NA90TM	 FQB2NA90TM
D FQB2P25TM	 FQB2P25TM	 FQB30N06	 FQB30N06L	 FQB30N06LTM
 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM	 FQB32N12V2	 FQB32N12V2TM
 FQB32N20	 FQB32N20C	D FQB32N20CTM	 FQB32N20CTM	 FQB32N30
 FQB33N10	D FQB33N10L	 FQB33N10LTM	 FQB33N10LTM	 FQB33N10TM
 FQB33N10TM	 FQB34N20	 FQB34N20L	 FQB34N20LTM	 FQB34N20LTM
 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10	D FQB34P10TM	 FQB34P10TM
 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM	 FQB3N30TM	 FQB3N30TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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